

SiC Schottky Barrier Diode

V_R	650V
I _F	2A
Q_{C}	6nC

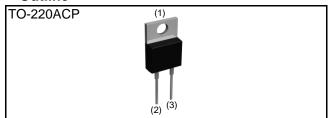
Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

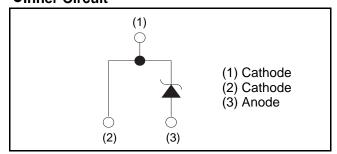
Construction

Silicon carbide epitaxial planar type

●Outline



●Inner Circuit



Packaging Specifications

	Packaging	Tube
	Reel size (mm)	-
Typo	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
Packing code		C9
	Marking	SCS302AH

● Absolute Maximum Ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	epetitive peak)	V_{RM}	650	V
Reverse voltage (D	C)	V_R	650	V
Continuous forward	l current (T _c =145°C)	I _F	2.15	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		19	A
repetitive forward	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	16	A
current	PW=10μs square, T _j =25°C		70	А
Repetitive peak forward current		I _{FRM}	12 ^{*1}	А
1≦PW≦10ms, T _j =25°C		.∫ i²dt	1.8	A ² s
i ² t value 1≦PW≦10ms, T _j =150°C		J i*dt	1.2	A ² s
Total power disspation		P_{D}	22 *2	W
Junction temperature		Tj	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

Parameter Symbol Cond	Cymbol	Conditions	Values			l loit
	Conditions	Min.	Тур.	Max.	Unit	
DC blocking voltage	V_{DC}	I _R =10.8μA	650	-	-	V
	V _F	I _F =2A,T _j =25°C	-	1.35	1.50	V
Forward voltage		I _F =2A,T _j =150°C	-	1.44	1.71	V
		I _F =2A,T _j =175°C	-	1.50	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	-	0.0065	10.8	μΑ
		V _R =650V,T _j =150°C	-	0.43	43	μΑ
		V _R =650V,T _j =175°C	-	1.29	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	110	-	pF
		V _R =650V,f=1MHz	-	10	-	pF
Total capacitive charge	Q_{C}	V _R =400V,di/dt=350A/μs	-	6	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	11	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	18	1	mJ

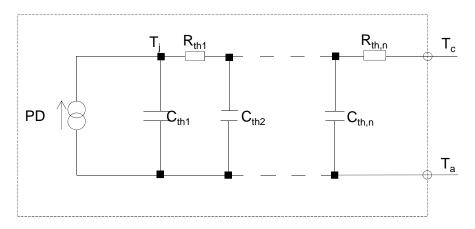
●Thermal characteristics

Parameter	Symbol	l Conditions	Sumbol Conditions Values				Unit
Parameter	Symbol		Min.	Тур.	Max.	Offic	
Thermal resistance	R _{th(j-c)}	-	-	4.5	6.7	°C/W	

●Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	8.21E-02	
R _{th2}	5.99E-01	K/W
R _{th3}	3.80E+00	

Symbol	Value	Unit
C _{th1}	6.35E-05	
C _{th2}	2.10E-04	Ws/K
C _{th3}	8.17E-04	



•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

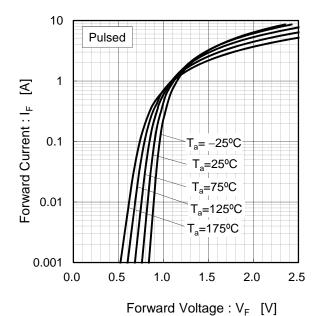


Fig.2 V_F - I_F Characteristics

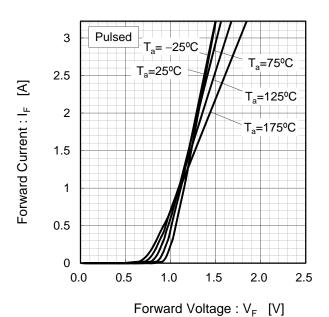


Fig.3 V_R - I_R Characteristics

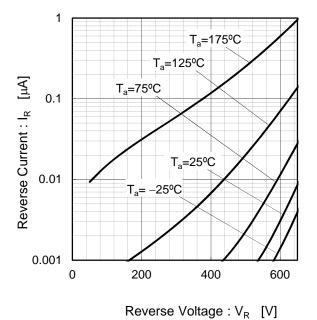
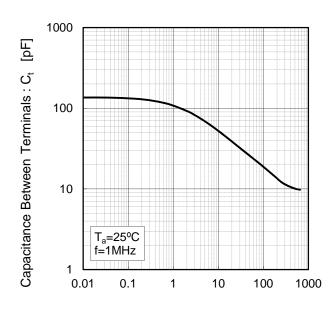


Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

•Electrical characteristic curves

Fig.5 Typical Transient Thermal Resistance vs. Pulse Width

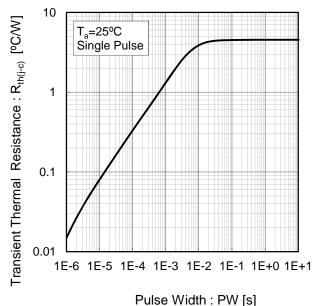
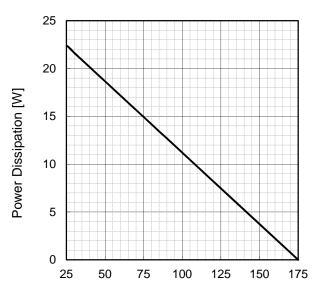
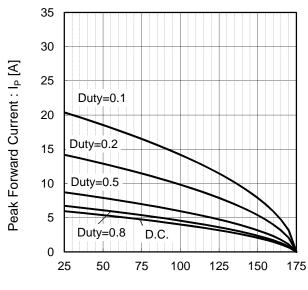


Fig.6 Power Dissipation



Case Temperature : T_c [°C]

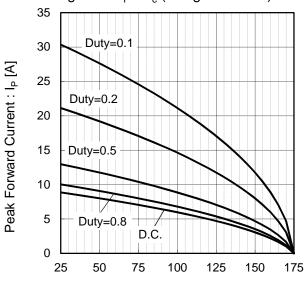
Fig.7*3 Maximum peak forward current derating curve $I_P - T_c$



Case Temperature : T_c [°C]

*3 Based on max Vf, max $R_{th(i\text{-}c)}$ Valid for switching of above 10kHz, excluding D.C. curve.

Fig.8*4 Typical peak forward current derating curve $I_P - T_c$ (Not guaranteed)



Case Temperature : T_c [°C]

 $^{\star}4$ Based on typ Vf, typ $R_{th(j\text{-}c)}$ Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)

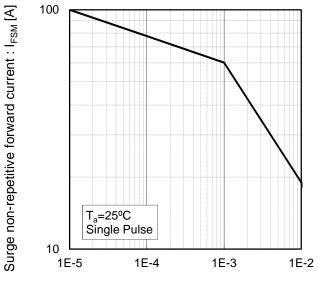
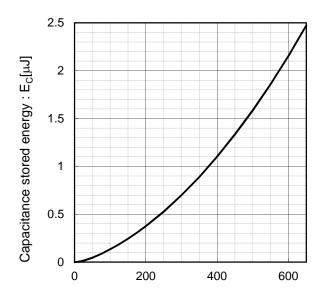


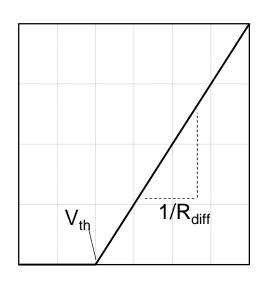
Fig.10 Typical capacitance store energy



Reverse Voltage: V_R [V]

Fig.11 Equivalent forward current curve

Pulse Width: PW [s]



Forward Voltage : V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value	Unit
a_0	9.66E-01	V
a ₁	- 1.10E-03	V/°C
b_0	1.64E-01	Ω
b ₁	3.47E-04	Ω/°C
b ₂	3.57E-06	Ω /°C ²

 T_{i} in ${}^{\circ}C$; -55 ${}^{\circ}C$ < T_{i} < 175 ${}^{\circ}C$; I_{F} < 4A

Forward Current: IF

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SCS302AHG - Web Page

Distribution Inventory

Part Number	SCS302AHG
Package	TO-220ACP
Unit Quantity	1000
Minimum Package Quantity	50
Packing Type	Tube
Constitution Materials List	inquiry
RoHS	Yes